T Number	Uita	Coamph Tout	חם	Time stamp
L Number	Hits 10	Search Text (("5999308") or ("5990850") or ("6064511")	DB USPAT;	Time stamp 2003/04/17 17:47
-	10	or ("5335240") or ("5998298")).PN.	US-PGPUB;	2003/04/17 17.47
	1	01 (3333240) 01 (3330230)/.1111.	EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	647	photonic and semiconductor and substrate	USPĀT;	2003/04/15 18:35
		and stack\$4	US-PGPUB;	
			EPO; JPO;	
!	1		DERWENT;	
			IBM TDB	
-	643	photonic and semiconductor and substrate	USPAT;	2003/04/15 14:41
		and stack\$4	US-PGPUB	
-	4	photonic and semiconductor and substrate	EPO; JPO;	2003/04/15 14:41
	i	and stack\$4	DERWENT;	
			IBM_TDB	
-	406	photonic and semiconductor and substrate	USPAT;	2003/04/15 14:43
		and stack\$4 and dielectric and material	US-PGPUB	
-	27	359/321 and photonic and semiconductor and	USPAT;	2003/04/15 18:41
		substrate	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
1_	49	350/344 and photonic and comiconduction	IBM_TDB	2003/04/15 18:46
1 -	49	359/344 and photonic and semiconductor and substrate	USPAT; US-PGPUB;	2003/04/13 18:46
		Substrate	EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	9	359/585 and photonic and semiconductor and	USPAT;	2003/04/15 18:46
		substrate	US-PGPUB;	2003,01,20 20110
!			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	16	359/586 and photonic and semiconductor and	USPAT;	2003/04/15 18:47
		substrate	US-PGPUB;	
			EPO; JPO;	
1			DERWENT;	
	ŀ		IBM_TDB	
-	9	The state of the s	USPAT;	2003/04/15 18:48
		substrate	US-PGPUB;	
1			EPO; JPO;	
	i		DERWENT;	
	13	250/500 and managed and annihilation and	IBM_TDB	2003/04/15 18:48
-	13	359/588 and photonic and semiconductor and substrate	USPAT; US-PGPUB;	2003/04/13 18:48
		Substitute	EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	7	343/911R and photonic and semiconductor	USPAT;	2003/04/24 14:17
	·	and substrate	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	93	372/43 and photonic and semiconductor and	USPĀT;	2003/04/15 19:59
		substrate	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		000/45	IBM_TDB	0000 (04 /05 05 05
-	176	372/45 and photonic and semiconductor and	USPAT;	2003/04/24 14:17
		substrate	US-PGPUB;	
			EPO; JPO;	
			DERWENT; IBM TDB	
_	۰ ا	372/451 and photonic and semiconductor and	USPAT;	2003/04/15 21:24
		substrate	US-PGPUB;	2003/03/13 21.24
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
	·			

-	98	385/131 and photonic and semiconductor and substrate	USPAT; US-PGPUB;	2003/04/15 21:34
			EPO; JPO; DERWENT;	
-	10	385/13 and photonic and semiconductor and	IBM_TDB USPAT; US-PGPUB;	2003/04/15 21:35
		Substrace	EPO; JPO; DERWENT;	
_	62	385/132 and photonic and semiconductor and	IBM_TDB USPAT;	2003/04/24 14:17
		substrate	US-PGPUB; EPO; JPO;	
	_		DERWENT; IBM_TDB	
-	5	438/690,697.ccls. and photonic and semiconductor and substrate	USPAT; US-PGPUB;	2003/04/24 14:24
			EPO; JPO; DERWENT; IBM TDB	
_	2	("5937118").PN.	USPAT; US-PGPUB;	2003/04/15 21:41
			EPO; JPO; DERWENT;	
_	74	, (, (IBM_TDB USPAT;	2003/04/17 17:50
		dielectric) and (photonic adj (crystal\$4 or band\$1gap\$2))	US-PGPUB; EPO; JPO; DERWENT;	
_	67	(first near2 dielectric) and (second near2	IBM_TDB USPAT;	2003/04/17 17:50
		<pre>dielectric) and (photonic adj (crystal\$4 or band\$1gap\$2))</pre>	US-PGPUB; EPO; JPO;	
			DERWENT; IBM_TDB	
-	45	<pre>(first near1 dielectric) and (second near1 dielectric) and (photonic adj (crystal\$4 or band\$1gap\$2))</pre>	USPAT; US-PGPUB; EPO; JPO;	2003/04/17 18:04
		or bandy1gapy2//	DERWENT; IBM TDB	
-	2	(first near3 dielectric) and (second near3 dielectric) and (photonic adj (crystal\$4	USPAT; US-PGPUB;	2003/04/17 18:25
		or band\$1gap\$2)) and (semiconductor near substrate)	EPO; JPO; DERWENT;	
-	15	 257/21 and (photonic adj (bandgap or band-gap or crystal\$1))	IBM_TDB USPAT; US-PGPUB;	2003/04/17 18:06
			EPO; JPO; DERWENT;	
-	69	430/\$.ccls. and photonic and semiconductor	IBM_TDB USPAT;	2003/04/24 14:21
		and substrate	US-PGPUB; EPO; JPO; DERWENT;	
_	5	430/\$.ccls. and photonic.ti.	IBM_TDB USPAT;	2003/04/24 12:28
			US-PGPUB; EPO; JPO;	
	1	((430/\$).CCLS. AND PHOTONIC AND	DERWENT; IBM_TDB USPAT;	2003/04/24 12:29
		SEMICONDUCTOR AND SUBSTRATE) and 6274293.PN.	US-PGPUB; EPO; JPO;	
			DERWENT; IBM_TDB	
-	1165	photonic.ti.	USPAT; US-PGPUB;	2003/04/24 12:45
			EPO; JPO; DERWENT; IBM TDB	
<u> </u>	·	L	, <u>-</u>	·

-		138	photonic.ti. and forming and etching	USPAT;	2003/04/24 12:45
				US-PGPUB;	
				EPO; JPO;	
				DERWENT;	
		128	photonic.ti. and forming and etching	IBM_TDB USPAT;	2003/04/24 12:46
-		120	photonic.ti. and forming and etching	US-PGPUB	2003/04/24 12:46
_		64	photonic.ti. and forming and etching and	USPAT:	2003/04/24 12:47
		0.1	Photonic near (crystal or bandgap)	US-PGPUB	2000/01/21 12:11
-		l 0	343/900 and photonic and semiconductor and	USPAT;	2003/04/24 14:37
			substrate	US-PGPUB;	
				EPO; JPO;	
				DERWENT;	
				IBM_TDB	
-		115		USPAT;	2003/05/01 10:25
			semiconductor and substrate	US-PGPUB;	
				EPO; JPO;	
				DERWENT;	
		7	430/604 and ababasis and sominandustry and	IBM_TDB	2002/04/24 14.24
-		'	438/694 and photonic and semiconductor and substrate	USPAT; US-PGPUB;	2003/04/24 14:24
			Substrate	EPO; JPO;	
				DERWENT;	
			l i	IBM TDB	
-		58	257/21 and photonic and semiconductor and	USPAT;	2003/04/24 14:26
			substrate	US-PGPUB;	
				EPO; JPO;	
				DERWENT;	
				IBM_TDB	
-		71	,,,,,,,		2003/04/24 15:19
			and photonic and semiconductor and	US-PGPUB;	
			substrate	EPO; JPO;	
				DERWENT;	
		71	359/322,245,250,321,327,238,226,332,248.ccl	IBM_TDB	2003/04/24 15:16
-		/1	and photonic and semiconductor and	US-PGPUB	2003/04/24 13:16
_		2086	phbsomateand semiconductor and substrate	USPAT;	2003/04/24 14:43
		2000	phobolaceand semiconductor and substrate	US-PGPUB	2003/04/24 14.45
-		2	343/786,772.ccls. and photonic and	USPAT;	2003/04/24 15:17
		_	semiconductor and substrate	US-PGPUB	
-	i	7,2	359/322,245,250,321,237,238,226,332,248.ccl	SUSPAT;	2003/04/24 15:20
			and photonic and semiconductor and	US-PGPUB;	
Ì			substrate	EPO; JPO;	
				DERWENT;	
1			1,550,444,45	IBM_TDB	0000/05/01 10 0/
-		98	· · · · ·	USPAT;	2003/05/01 10:26
1			semiconductor and substrate	US-PGPUB; EPO; JPO;	
				DERWENT;	
				IBM TDB	
_		1	("5739796").PN.	USPAT	2004/04/18 19:45
-			(("5999308") or ("5990850") or ("6064511")	USPAT	2004/04/18 20:01
	l		or ("5335240") or ("5998298") or		
	[("6521136")).PN.		
-		0	359/321,245,250,332,238,344,585,586,587,588	uspat	2004/04/18 20:03
	Ī		and photonic.dclm.		
-		34	359/321,245,250,332,238,344,585,586,587,588	USPAT	2004/04/18 20:04
		_	and photonic.ti.	Hann	2004/04/10 22 22
-		3	("3654809" "5740287" "6262830").PN.	USPAT	2004/04/18 20:31
-	ļ	35	359/321,245,250,332,238,344,585,586,587,588 and photonic.ab.	Copat	2004/04/18 20:40
_		75	359/321,245,250,332,238,344,585,586,587,588	AKTPAT	2004/04/18 20:39
			and photonic.bsum.		
-	1	34	359/321,245,250,332,238,344,585,586,587,588	USPAT	2004/04/18 20:41
			and photonic.clm.		
-		2465	photonic.ab.	EPO; JPO;	2004/04/18 20:52
				DERWENT;	
				IBM_TDB	
-		611	photonic.clm.	USPAT	2004/04/18 20:42
-		611 502 2168	<pre>photonic.clm. photonic.ab. photonic.bsum.</pre>	USPAT USPAT USPAT	2004/04/18 20:42 2004/04/18 20:42 2004/04/18 20:42

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-	342	photonic.clm. and photonic.ab. and photonic.bsum.	USPAT	2004/04/18 20:42
-	211	•	USPAT	2004/04/18 20:43
	1435	•	EPO; JPO; DERWENT; IBM TDB	2004/04/18 20:52
-	635	photonic.ti. and crystal	EPO; JPO; DERWENT;	2004/04/18 20:53
-	86	photonic.ti. and crystal and dielectric	IBM_TDB EPO; JPO; DERWENT;	2004/04/18 20:53
			IBM TDB	